Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material: Metal Overall Length: 0.475 inches

**Mounting Facility Quantity:** 

1

#### Mounting Method:

Threaded stud

**Thread Size:** 

0.250 inches

Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

400.0 breakover voltage, dc

**Current Rating Per Characteristic:** 

80.00 amperes forward current, average absolute

## Power Rating Per Characteristic:

500.0 milliwatts small-signal input power, common-collector blank

## Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius junction

# **Thread Series Designator:**

Unf

## **Terminal Type And Quantity:**

2 tab, solder lug and 1 threaded stud

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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